SAMPLE PAPER (TITLE)

 First Middle Last (author 1)1, First Middle Last (author 2)1\*,
First Middle Last (Last author)2

 1Dept. name of organization (of Affiliation), Name of organization (of Affiliation), City, Country

2Dept. name of organization (of Affiliation), Name of organization (of Affiliation), City, Country

\*Corresponding author: single corresponding author email address

***ABSTRACT:*** Use the styles provided in this document to write your paper. You will find style name between brackets at the end of character or paragraph. (Normal).

KEY WORDS: Font, Style, and Formatting. (Normal + title case). [Maximum five]

1. INTRODUCTION (HEADING 1)

In an attempt to make formatting easy, you can use the style menu just under the standard menu. Every button has a name similar to style name in brackets after each paragraph. (Normal).

1. ORGANIZING YOUR PAPER (HEADING 1)

Leave spaces inside the text for figures and tables (keep figure caption in its space). Avoid using tab or enter buttons whenever possible. (Normal).

* 1. **Illustrations (Heading 2)**

Tables and figure should be placed at the end of the paper; each figure should be in a separate A4 size page. (Normal).

### ***Figures, Tables, and Graphs (Heading 3)***

To refer to a figure or a table in the text write; refer to Fig. 1 (for example). Figure caption should be written outside the figure or the table (not attached to the figure). Figures numbering should be absolute (not according to section numbers), for example: Fig. 1, Fig. 2, Fig. 3…. etc. (Normal).



Fig. 1. Return loss and resonant of the antenna for different types of MEMS bridge materials when the switches are ON.

Figures and table size should be as suitable as to fit in two-column page according to our journal format (see enclosed sample). Leave an empty space in the place of the figure using figure space style button. Put table title before the table and use table title style for it For example (Normal).

Table 1: Example system technical data (table title)

|  |  |  |  |  |
| --- | --- | --- | --- | --- |
| **Station** | **System Type** | **Length [m]** | **Diameter [m]** | **Mass [kg]** |
| **1** | ABC-9X | 2.951 | 0.123 | 66.00 |
| **2** | ABC-10Y | 4.466 | 0.145 | 144.88 |
| **3** | ABC-100Z | 3.011 | 0.167 | 155.99 |

### ***Equations (Heading 3)***

Write Equations and symbols using Microsoft equation editor or Mathtype. Equation numbering should be absolute as we did with figures. In addition, write refer to Eq. (1) if you want to refer to equation number 1 and write refer to Eq. (2) if you want to refer to equation number 2 and so on. Use only one Tab space between equation and its number.

If you want to refer to a paper or a book, write the number of the paper or the book that is corresponding to it in the Reference section. Use the style provided (refer), for example; write [1] wherever you want to refer to article number 1. Start with article number one then number two and so on. It is important also to arrange the references in the references section according to their appearance order in the text.

$rate=W\_{q}k\_{f}(\frac{a\_{MTBE}}{K\_{eq}a\_{MeOH}^{2}})$ (1)

1. CONCLUSION REMARKS (HEADING 1)

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• Use only simple format for your paper. (List)

ACKNOWLEDGEMENT (ACKNOW)

The acknowledgements come at the end of an article after the conclusions and before the references

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